NCE N-Channel Super Trench Power MOSFET

Description

The NCEP15T14 uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

General Features

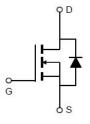
- V_{DS} =150V, I_D =140A $R_{DS(ON)}$ =5.8m Ω , typical @ V_{GS} =10V
- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

Application

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

100% UIS TESTED!

100% AVds TESTED!



Schematic diagram



Marking and pin assignment



TO-220-3L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP15T14	NCEP15T14	TO-220-3L	-	-	-

Absolute Maximum Ratings (T_C=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	150	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	140	Α
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	100	Α
Pulsed Drain Current	I _{DM}	560	А
Maximum Power Dissipation	P _D	320	W
Derating factor		2.1	W/°C
Single pulse avalanche energy (Note 1)	Eas	1296	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 175	$^{\circ}$

Thermal Characteristic

Thermal Resistance,Junction-to-Case	R _{θJC}	0.47	°C/W
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Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Off Characteristics							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	150	-	-	V	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =150V,V _{GS} =0V	-	-	1	μA	
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA	
On Characteristics							
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250μA	2.0	3.0	4.0	V	
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =70A	-	5.8	6.5	mΩ	
Forward Transconductance	g FS	V _{DS} =10V,I _D =70A	70	-	-	S	
Dynamic Characteristics							
Input Capacitance	C _{lss}	\\ 75\\\\ 0\\	-	6000	-	pF	
Output Capacitance	Coss	V_{DS} =75 V , V_{GS} =0 V ,	-	690	-	pF	
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	24	-	pF	
Switching Characteristics (Note 2)			<u> </u>	•			
Turn-on Delay Time	t _{d(on)}		-	26	-	nS	
Turn-on Rise Time	t _r	V_{DD} =75 V , I_D =70 A	-	36	-	nS	
Turn-Off Delay Time	t _{d(off)}	$V_{GS}\text{=}10V,R_{G}\text{=}4.7\Omega$	-	47	-	nS	
Turn-Off Fall Time	t _f		-	15	-	nS	
Total Gate Charge	Qg	\/ 75\/ 704	-	80	-	nC	
Gate-Source Charge	Q _{gs}	$V_{DS}=75V,I_{D}=70A,$	-	32	-	nC	
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	22	-	nC	
Drain-Source Diode Characteristics							
Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _F = I _S	-	-	1.2	V	
Diode Forward Current	Is		-	-	140	Α	
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F = I _S	-	146	-	nS	
Reverse Recovery Charge	Qrr	di/dt = 100A/μs	-	485	-	nC	

Notes:

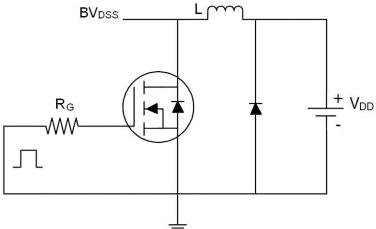
^{1.} EAS condition : Tj=25 $^{\circ}\text{C}$,V_DD=50V,V_G=10V,L=0.5mH,Rg=25 Ω

^{2.} Guaranteed by design, not subject to production

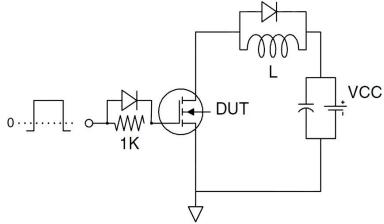
^{3.} These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of TJ(MAX)=175° C. The SOA curve provides a single pulse rating.

Test Circuit

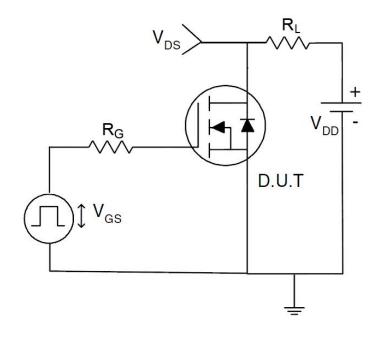
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit



Typical Electrical and Thermal Characteristics

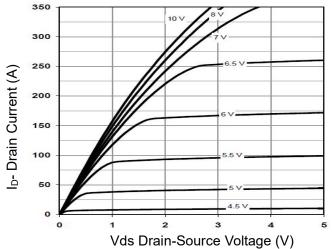


Figure 1 Output Characteristics

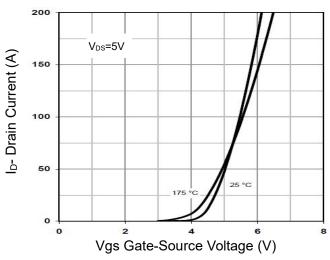


Figure 2 Transfer Characteristics

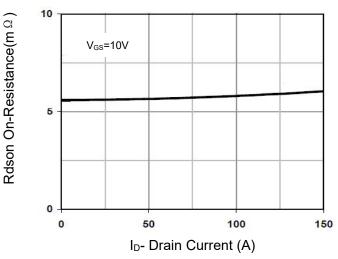


Figure 3 Rdson- Drain Current

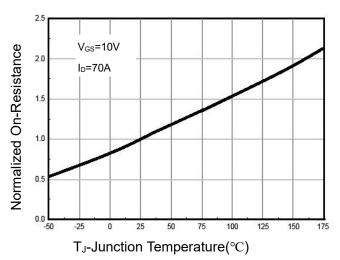


Figure 4 Rdson-JunctionTemperature

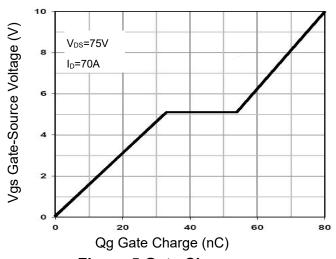


Figure 5 Gate Charge

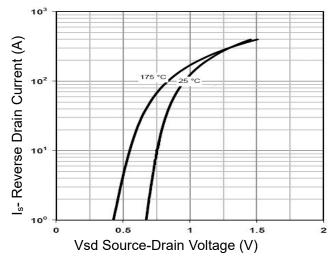
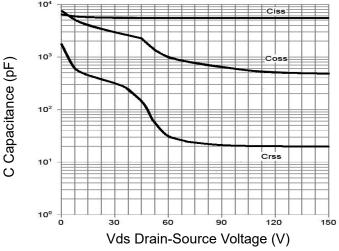


Figure 6 Source- Drain Diode Forward





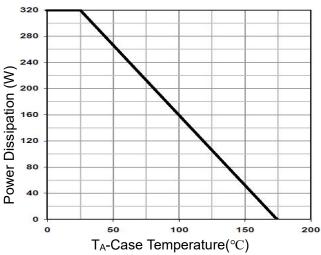
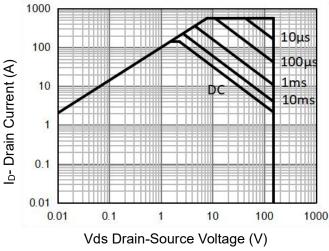


Figure 7 Capacitance vs Vds Figure 9 Power De-rating



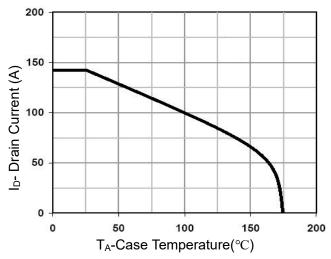


Figure 8 Safe Operation Area(Note3)

Figure 10 Current De-rating

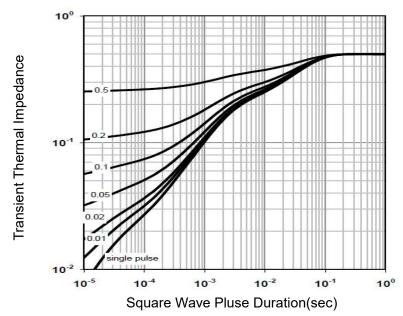
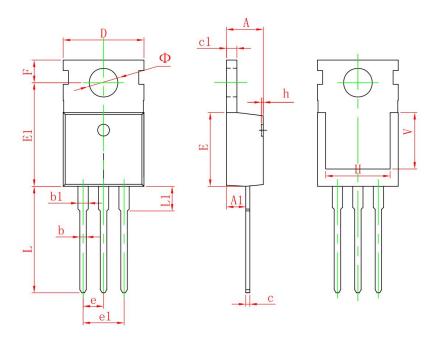


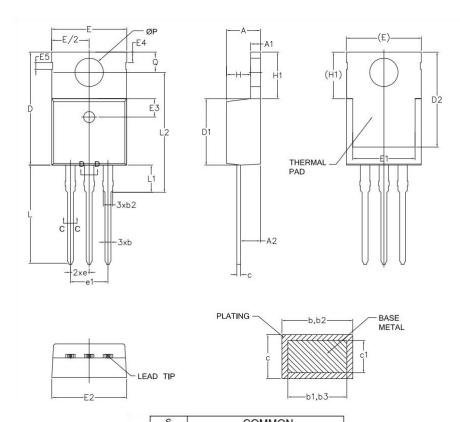
Figure 11 Normalized Maximum Transient Thermal Impedance

TO-220-3L(C) Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E	8.950	9.750	0.352	0.384	
E1	12.650	13.050	0.498	0.514	
е	2.540	TYP.	0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	6.900	REF.	0.276 REF.		
Ф	3.400	3.800	0.134	0.150	

TO-220-3L(J) Package Information



SYMBOLS		COMMON MM				
1	Α	4.47	4.57	4.67		
	A1	1.20	1.30	1.40		
	A2	2.35	2.67	2.90		
	b	0.71	0.80	0.91		
	b1	0.71	0.80	0.86		
	b2	1.22	1.27	1.36		
1	b3	1.22	1.27	1.31		
1	С	0.47	0.50	0.60		
	c1	0.47	0.50	0.55		
	D	14.70	15.30	15.80		
	D1	8.90	9.00	9.47		
	D2	11.75	/	13.60		
2	Е	9.70	/	10.37		
	E1	7.00	8.44	8.89		
	E2	9.80	10.11	10.20		
	E3	2.40	2.50	2.60		
	E4	1.27	1.42	1.57		
	E5	0.90TYP				
	е	2.54BSC				
	e1	5.08BSC				
	Н	3.00	3.27	3.40		
[H1	6.15	6.30	6.45		
	L	12.90	13.45	14.80		
	L1	2.54	3.69	3.84		
	L2	12.13	16.25	16.5		
3	ØΡ	3.60	3.84	3.90		
	Q	2.65	2.74	2.95		

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